NSN 5961-01-369-6980

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Internal Configuration:

Junction contact

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

3.5 breakdown voltage, emitter-to-base, collector open and 65.0 breakdown voltage, collector-to-emitter, with base short-circuited to emitter and 25.0 breakdown voltage, collector-to-emitter, base open and 65.0 breakdown voltage, collector-to-base, emitter open

Current Rating Per Characteristic:

35.00 milliamperes base current, dc preset

Power Rating Per Characteristic:

600.00 milliwatts large-signal input power, common-emitter preset

Transfer Ratio:

200.0 static forward current transfer ratio, common-emitter

Special Features:

Junction pattern arrangement: npn

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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